

2SB1079

Silicon PNP Triple Diffused

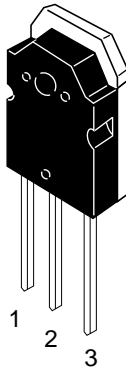
HITACHI

Application

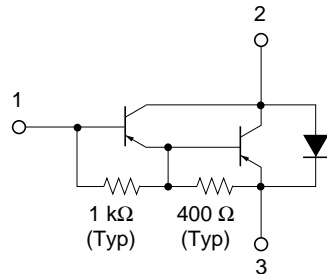
Low frequency power amplifier complementary pair with 2SD1559

Outline

TO-3P



- 1. Base
- 2. Collector (Flange)
- 3. Emitter



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	-100	V
Collector to emitter voltage	V_{CEO}	-100	V
Emitter to base voltage	V_{EBO}	-7	V
Collector current	I_{C}	-20	A
Collector peak current	$I_{\text{C(peak)}}$	-30	A
Base current	I_{B}	-3	A
Collector power dissipation	P_{C}^{*1}	100	W
Junction temperature	T_{j}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

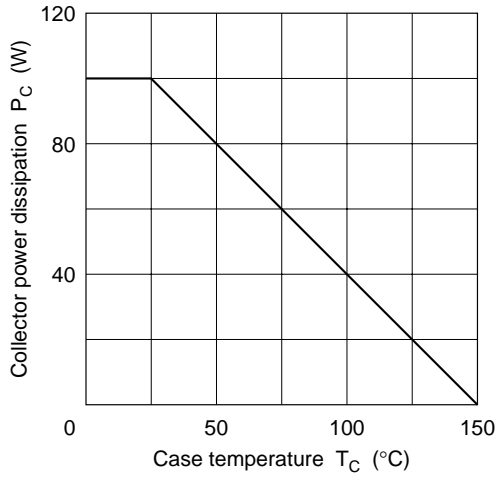
Note: 1. Value at $T_{\text{C}} = 25^\circ\text{C}$.

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

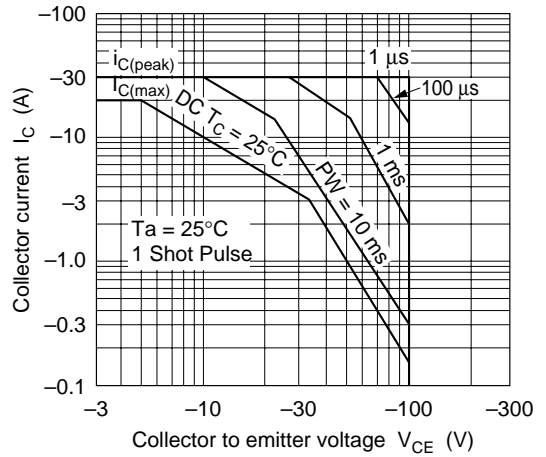
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	-100	—	—	V	$I_{\text{C}} = -0.1 \text{ mA}$, $I_{\text{E}} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	-100	—	—	V	$I_{\text{C}} = -25 \text{ mA}$, $R_{\text{BE}} = \infty$
Collector to emitter sustain voltage	$V_{\text{CEO(sus)}}$	-100	—	—	V	$I_{\text{C}} = -200 \text{ mA}$, $R_{\text{BE}} = \infty^{*1}$
Emitter to base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	-7	—	—	V	$I_{\text{E}} = -50 \text{ mA}$, $I_{\text{C}} = 0$
Collector cutoff current	I_{CBO}	—	—	-100	μA	$V_{\text{CB}} = -100 \text{ V}$, $I_{\text{E}} = 0$
	I_{CEO}	—	—	-1.0	mA	$V_{\text{CE}} = -80 \text{ V}$, $R_{\text{BE}} = \infty$
DC current transfer ratio	h_{FE}	1000	—	20000		$V_{\text{CE}} = -3 \text{ V}$, $I_{\text{C}} = -10 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)1}}$	—	—	-2.0	V	$I_{\text{C}} = -10 \text{ A}$, $I_{\text{B}} = -20 \text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{\text{BE(sat)1}}$	—	—	-2.5	V	
Collector to emitter saturation voltage	$V_{\text{CE(sat)2}}$	—	—	-3.0	V	$I_{\text{C}} = -20 \text{ A}$, $I_{\text{B}} = -200 \text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{\text{BE(sat)2}}$	—	—	-3.5	V	
Turn on time	t_{on}	—	0.6	—	μs	$I_{\text{C}} = -10 \text{ A}$, $I_{\text{B1}} = -I_{\text{B2}} = -20 \text{ mA}$
Storage time	t_{stg}	—	3.5	—	μs	

Note: 1. Pulse Test.

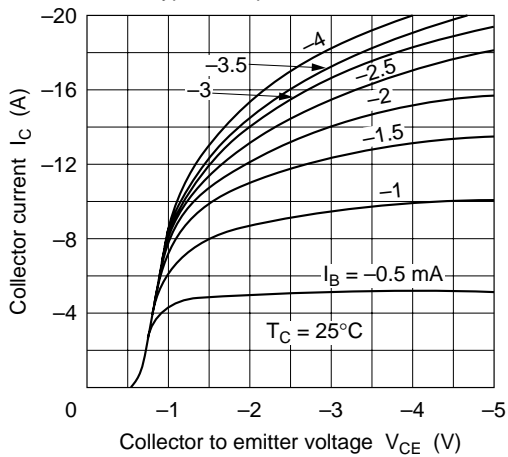
Maximum Collector Dissipation Curve



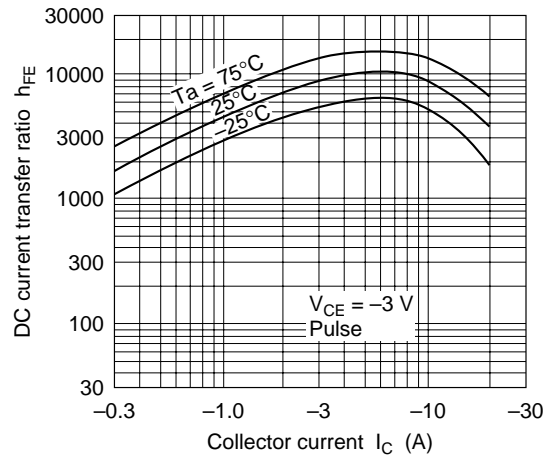
Area of Safe Operation

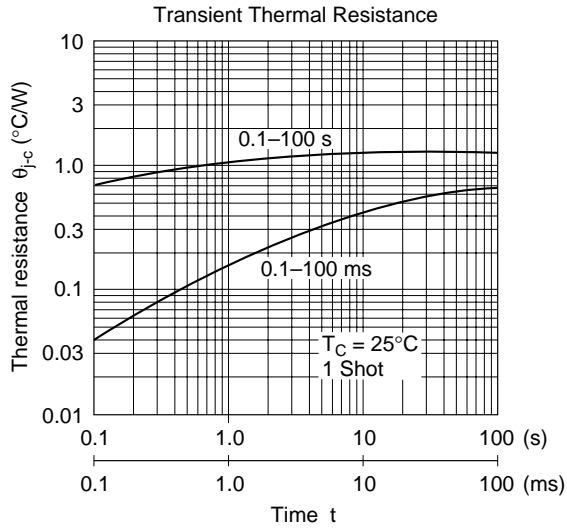
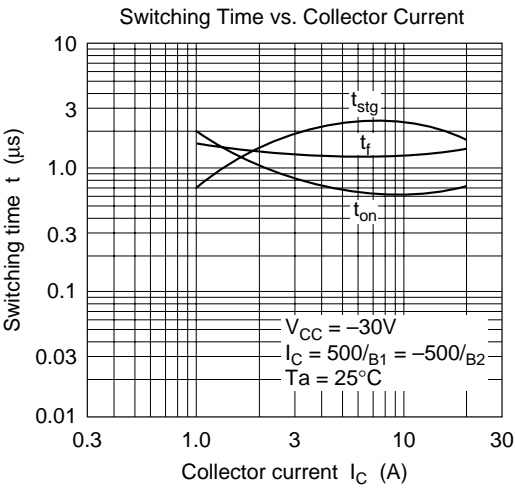
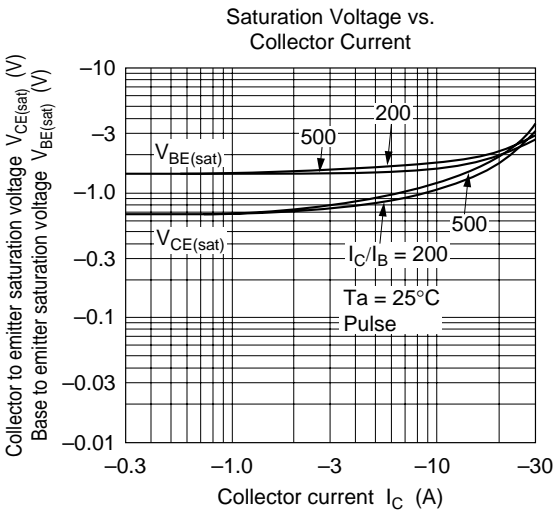


Typical Output Characteristics

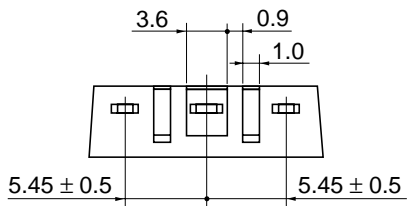
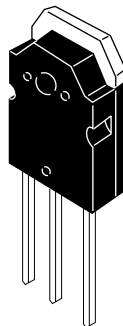
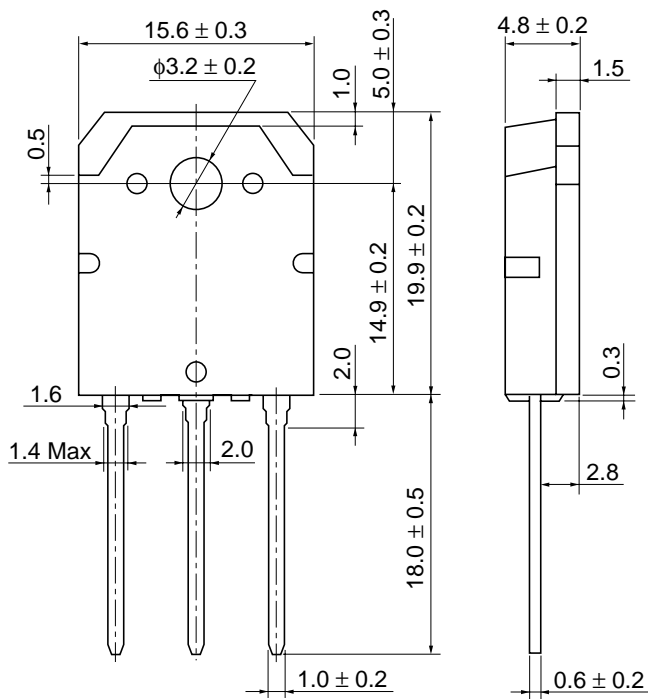


DC Current Transfer Ratio vs. Collector Current





Unit: mm



Hitachi Code	TO-3P
JEDEC	—
EIAJ	Conforms
Weight (reference value)	5.0 g

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